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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

8888

plicants:

Cher Huan TAN et al.

Group Art Unit:

Election Lagar Election Lagar T. S. Pham 9-3-02

Serial No.:

10/025,085

Examiner:

Filed:

December 19, 2001

For: "

Method For Preventing Photoresist Poisoning In

Semiconductor Fabrication

RESPONSE TO RESTRICTION REQUIREMENT DATED JULY 9, 2002

Assistant Commissioner for Patents Washington, D.C. 20231

Att'y. Docket No. 2085-00600 Client Ref. No. IME-P002US/fmk

Date: August 7, 2002

Sir:

This paper is filed in response to the Restriction Requirement dated July 9, 2002. The Examiner is requested to enter the following amendments and consider the accompanying remarks.

Reconsideration is respectfully requested.

AMENDMENT

IN THE CLAIMS:

Applicants hereby respectfully requests amendments to claims 1, 11, 12 and 16, by replacement with rewritten claims 1, 11, 12 and 16, as follows:

(Once Amended) In a via-first dual damascene process involving the use of a low-K dielectric material as an insulation layer on a wafer substrate during the fabrication of an integrated circuit, a method for photolithographic patterning comprising the steps of:

filling an aperture etched into an insulation layer on a wafer substrate with a fill-in material

5 for isolating the insulation layer from photoresist deposited thereafter;

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